

# Knobbe Martens Olson & Bear LLP

Intellectual Property Law



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December 7, 2006

## Certificate

DEC 14 2006

## of Correction

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Re: Title: INTERLAYER INSULATION FILM USED FOR MULTILAYER  
INTERCONNECT OF SEMICONDUCTOR INTEGRATED CIRCUIT AND  
METHOD OF MANUFACTURING THE SAME  
Letters Patent No. 7,098,129  
Issued: August 29, 2006  
Our Reference: ASMJP.134AUS

Dear Sir:

Enclosed for filing is a Certificate of Correction in connection with the above-identified patent.

As the errors cited in the Certificate of Correction were incurred through the fault of the Applicant, enclosed is our check in the amount of \$100. Please charge any additional fees to our Deposit Account No. 11-1410.

Respectfully submitted,

Knobbe, Martens, Olson & Bear, LLP

Katsuhiro Arai  
Registration No. 43,315  
Customer No. 20,995

Enclosures

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San Diego  
619-235-8550

San Francisco  
415-954-4114

Los Angeles  
310-551-3450

Riverside  
951-781-9231

San Luis Obispo  
805-547-5580

# UNITED STATES PATENT AND TRADEMARK OFFICE

## CERTIFICATE OF CORRECTION

PATENT NO. : 7,098,129  
APPLICATION NO. : 10/657,416  
ISSUE DATE : August 29, 2006  
INVENTOR(S) : Naoto TSUJI, Fumitoshi OZAKI, Satoshi TAKAHASHI

Page 1 of 2

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the first page, at Column 2 (Other Publications), please delete "Sysmposium" and insert -- Symposium --, therefor.

On the first page, at Column 2 (Other Publications), please delete "Techology," and insert -- Technology,--, therefor.

At Column 3, line 11, after "may be," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane --, therefor.

At Column 10, line 41-42, after "DM-DMOS," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 11, line 11, after "DM-DMOS," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 13, line 37-38, after "hydrocarbon is," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 13, line 63, after "hydrocarbon is," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 15, line 10, after "the second gas is," please delete "dimethy-dimethoxysilane" and insert -- dimethyl-dimethoxysilane,-- therefor.

At Column 5, line 9, after "wherein," please delete "a" and insert --  $\alpha$  --, therefor.

At Column 5, line 66, after " $C_6H_5$ ," please delete " $C_3H_5$ ,  $C_3H_5$ ," and insert --  $C_3H_5$ ,--, therefor.

At Column 8, line 11, after "such as 1.5," please delete " $W/Cm^2$ " and insert --  $W/cm^2$  --, therefor.

### MAILING ADDRESS OF SENDER:

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DOCKET NO. ASMJP.134AUS

DEC 15 2006

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CERTIFICATE OF CORRECTION**

**PATENT NO.** : 7,098,129  
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At Column 9, line 18, after "become," please delete "unstabilized." And insert -- unstabilized.--  
therefor.

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